

Description

The XU devices are low phase noise quartz-based PLL oscillators supporting a large range of frequencies and output interface types. These devices are designed to operate at three different power supplies and are available in multiple package sizes as well as temperature grades.

With a patented one-time program (OTP) allowing for infinite memory shelf life, the XU devices can be programmed to generate an output frequency from 16kHz to 1500MHz with a resolution as low as 1Hz accuracy. The configuration capability of this family of devices allows for fast delivery times for both sample and large production orders.

Pin Assignments

NOTE: To minimize power supply line noise, a 0.01μF bypass capacitor should be placed between V_{DD} (Pin 6) and GND (Pin 3).

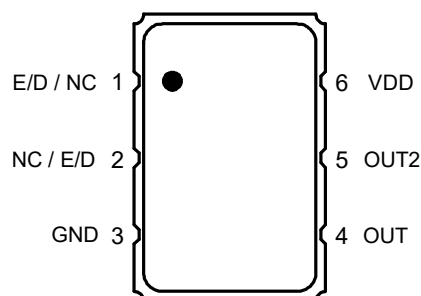


Table 1. Pin Description

Pin #	Name	Description
1	E/D NC	Enable/Disable ^{[a][b]} No connect
2	NC E/D	No connect Enable/Disable ^{[a][b]}
3	GND	Connect to ground
4	OUT	Output
5	OUT2	Complementary output ^[c]
6	V _{DD}	Supply voltage

[a] Pulled high internally = output enabled.

[b] Low = output disabled.

[c] Do not connect for LVCMOS. For XLVCMOS both OUT and OUT2 are ON and in opposite phase.

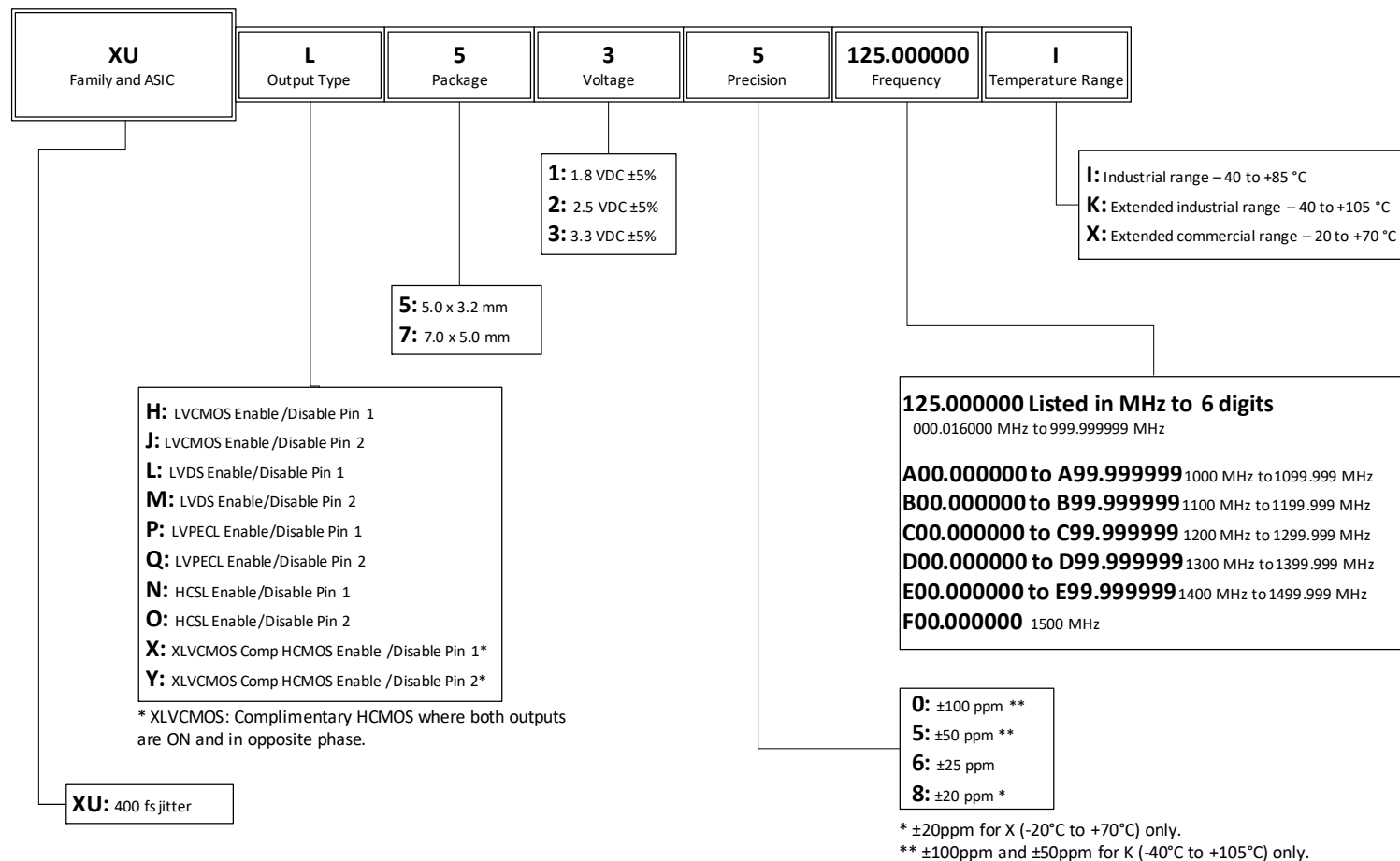
See [Ordering Information](#) for more details.

Features

- Frequency range: 0.016MHz to 1500MHz^[1]
- Output types: LVDS, LVPECL, HCSL, LVCMOS
- Supply voltage options: 1.8V, 2.5V, or 3.3V
- Phase jitter (1.875MHz to 20MHz): 100fs typical
- Phase jitter (12kHz to 20MHz): 300fs typical
- Package options:
 - 5.0 × 3.2 × 1.2 mm
 - 7.0 × 5.0 × 1.3 mm
- Operating temperature: -20°C to +70°C
 - Frequency stability options: ±20, ±25, ±50, or ±100 ppm
- Operating temperature: -40°C to +85°C
 - Frequency stability options: ±25, ±50, or ±100 ppm
- Operating temperature: -40°C to +105°C
 - Frequency stability options: ±50 or ±100 ppm

[1] There is a dead zone between 1037.5MHz to 1300MHz.
Contact [support](#) for frequencies above 1300MHz.

Ordering Information



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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the device. The ratings, which are standard values for Renesas commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Table 2. Absolute Maximum Ratings

Item	Rating			
V _{DD}	-0.5 to +5.0V			
E/D	-0.5V to V _{DD} + 0.5V			
OUT	-0.5V to V _{DD} + 0.5V			
Storage Temperature	-55°C to 125°C			
Maximum Junction Temperature	125°C			
Core Current	65mA maximum			
Theta J _A	JU6	75.9 °C/W	JS6	89.6 °C/W
Theta J _B		48.6 °C/W		54.3 °C/W

ESD Compliance

Table 3. ESD Compliance

Human Body Model (HBM)	1000V
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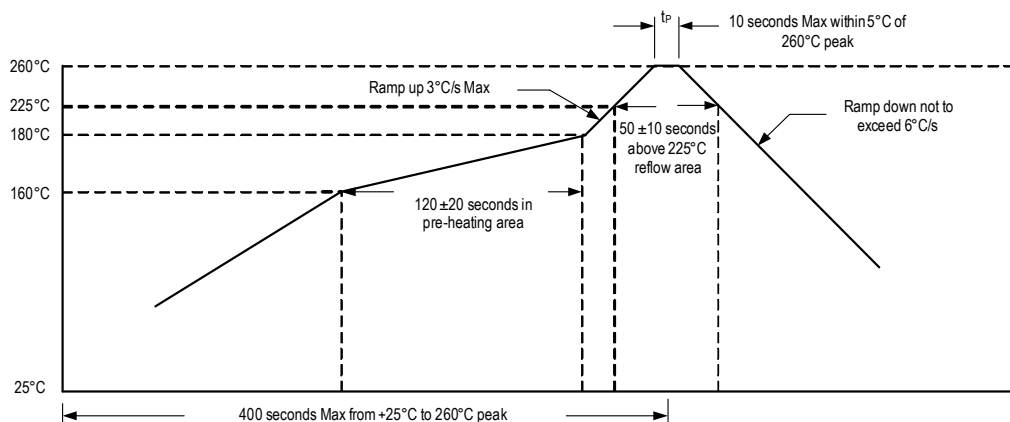
Mechanical Testing

Table 4. Mechanical Testing *

Parameter	Test Method
Mechanical Shock	Half-sine wave with 0.3ms 3000G. X, Y, Z each direction 1 time.
Mechanical Vibration	Frequency: 10 – 55MHz amplitude: 1.5mm. Frequency: 55 – 2000Hz peak value: 20G. Duration time: 4H for each X,Y,Z axis; total 12hours.
High Temp Operating Life (HTOL)	2000 hours at 125°C (under power).
Hermetic Seal	Gross leak (air leak test). Fine leak (Helium leak test) He-pressure: 6kgf/cm ² 2 hours.

* MSL level does not apply.

Solder Reflow Profile



DC Electrical Characteristics

Note for all DC Electrical Characteristics tables: A pull-up resistor from V_{DD} to E/D enables output when pin 1 is left open.

Table 5. 3.3V IDD DC Electrical Characteristics

$V_{DD} = 3.3V \pm 5\%$, $T_A = -20^\circ C$ to $+70^\circ C$; $-40^\circ C$ to $+85^\circ C$, $-40^\circ C$ to $+105^\circ C$.

Symbol	Parameter	Output Type	Conditions	Minimum	Typical	Maximum	Units
I_{DD}	Current Consumption	LVDS	0.016MHz to 400MHz.			97	mA
			400.000+MHz to 1.5GHz.			122	
		LVPECL	0.016MHz to 212.5MHz.			115	
			212.5+MHz to 400MHz.			128	
			400+MHz to 670MHz.			142	
		HCSL	0.016MHz to 670MHz.			145	
		LVCMOS	0.016MHz to 62.5MHz.			98	
			62.5+MHz to 167MHz.			108	

Table 6. 2.5V IDD DC Electrical Characteristics

$V_{DD} = 2.5V \pm 5\%$, $T_A = -20^\circ C$ to $+70^\circ C$; $-40^\circ C$ to $+85^\circ C$, $-40^\circ C$ to $+105^\circ C$.

Symbol	Parameter	Output Type	Conditions	Minimum	Typical	Maximum	Units
I_{DD}	Current Consumption	LVDS	0.016MHz to 400MHz.			90	mA
			400.000+MHz to 1.35GHz.			103	
		LVPECL	0.016MHz to 156.25MHz.			102	
			156.25+MHz to 400MHz.			112	
			400+MHz to 670MHz.			118	
		HCSL	0.016MHz to 400MHz.			102	
			400.000+MHz to 670MHz.			112	
		LVCMOS	0.016MHz to 62.5MHz.			80	
			62.5+MHz to 125MHz.			85	
			125+MHz to 167MHz.			92	

Table 7. 1.8V IDD DC Electrical Characteristics
 $V_{DD} = 3.3V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$.

Symbol	Parameter	Output Type	Conditions	Minimum	Typical	Maximum	Units
I_{DD}	Current Consumption	LVDS	0.016MHz to 400MHz.			65	mA
			400.000+MHz to 1.0GHz.			72	
		LVPECL	0.016MHz to 250MHz.			75	
			250.000+MHz to 670MHz.			97	
		HCSL	0.016MHz to 400MHz.			68	
			400.000+MHz to 670MHz.			77	
		LVC MOS	0.016MHz to 125MHz.			58	

Table 8. LVDS DC Electrical Characteristics
 $V_{DD} = 3.3V, 2.5V, 1.8V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$. Below are guaranteed for listed standard frequencies.

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{OD}	Differential Output Voltage		0.25	0.4	0.5	V
V_{OS}	Output Offset Voltage		1	1.17	1.375	
V_{IH}	Enable/Disable Input High Voltage		$70\%V_{DD}$			
V_{IL}	Enable/Disable Input Low Voltage				$30\%V_{DD}$	

Table 9. LVPECL DC Electrical Characteristics
 $V_{DD} = 3.3V, 2.5V, 1.8V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$. Below are guaranteed for listed standard frequencies.

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Output High Voltage	$V_{DD} = 3.3V \pm 5\%$.	1.85		2.3	V
		$V_{DD} = 2.5V \pm 5\%$.	1.1		1.45	
		$V_{DD} = 1.8V \pm 5\%$.	0.5		0.8	
V_{OL}	Output Low Voltage	$V_{DD} = 3.3V \pm 5\%$.	1.1		1.65	
		$V_{DD} = 2.5V \pm 5\%$.	0.35		0.85	
		$V_{DD} = 1.8V \pm 5\%$.	0		0.25	
V_{IH}	Enable/Disable Input High Voltage		$70\%V_{DD}$			
V_{IL}	Enable/Disable Input Low Voltage				$30\%V_{DD}$	

Table 10. HCSL DC Electrical Characteristics

$V_{DD} = 3.3V, 2.5V, 1.8V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$. Below are guaranteed for listed standard frequencies.

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Output High Voltage	$V_{DD} = 3.3V \pm 5\%$	0.6		1.1	V
		$V_{DD} = 2.5V \pm 5\%$	0.55		0.95	
		$V_{DD} = 1.8V \pm 5\%$	0.45		0.7	
V_{OL}	Output Low Voltage		0		0.2	
V_{IH}	Enable/Disable Input High Voltage		$70\%V_{DD}$			
V_{IL}	Enable/Disable Input Low Voltage				$30\%V_{DD}$	

Table 11. LVCMOS DC Electrical Characteristics

$V_{DD} = 3.3V, 2.5V, 1.8V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$. Below are guaranteed for listed standard frequencies.

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{OH}	Differential Output Voltage		$90\%V_{DD}$			V
V_{OL}	Output Offset Voltage				$10\%V_{DD}$	
V_{IH}	Enable/Disable Input High Voltage		$70\%V_{DD}$			
V_{IL}	Enable/Disable Input Low Voltage				$30\%V_{DD}$	

AC Electrical Characteristics

Table 12. 3.3V AC Electrical Characteristics
 $V_{DD} = 3.3V \pm 5\%$, $T_A = -20^{\circ}C$ to $+70^{\circ}C$; $-40^{\circ}C$ to $+85^{\circ}C$, $-40^{\circ}C$ to $+105^{\circ}C$.

Symbol	Parameter	Test Condition		Minimum	Typical	Maximum	Units
F	Output Frequency Range	LVDS.		0.016		1500	MHz
		LVPECL, HCSL.		0.016		670	
		LVCMOS.		0.016		167	
	Frequency Stability	Temperature = $-20^{\circ}C$ to $+70^{\circ}C$.		± 20		± 100	ppm
		Temperature = $-40^{\circ}C$ to $+85^{\circ}C$.		± 25		± 100	ppm
		Temperature = $-40^{\circ}C$ to $+105^{\circ}C$.		± 50		± 100	ppm
	Aging (1st year)	$T_A = 25^{\circ}C$.				± 3	
	Aging (10 years)	$T_A = 25^{\circ}C$.				± 10	
	Output Load	LVDS.	Differential.		100		Ω
		LVPECL.	$V_{DD} - 2.0V$.		50		
		HCSL.	To GND.		50		
		LVCMOS.	To GND.		15		pF
T_{ST}	Start-up Time	Output valid time after V_{DD} meets minimum specified level.				10	ms
t_R	Output Rise Time	LVDS.	20% to 80% Vpk-pk.		275	380	ps
		LVPECL.				400	
		HCSL.				330	
		LVCMOS.	10% to 90% V_{DD} .			3	ns
t_F	Output Fall Time	LVDS.	80% to 20% Vpk-pk.		275	380	ps
		LVPECL.				400	
		HCSL.				330	
		LVCMOS.	90% to 10% V_{DD} .			3	ns
O_{DC}	Output Clock Duty Cycle	LVDS.		45		55	%
		LVPECL.	$F_{OUT} \leq 312.5MHz$.	45		55	
			$F_{OUT} > 312.5MHz$.	40		60	
		HCSL.		45		55	
		LVCMOS.	$F_{OUT} \leq 62.5MHz$.	45		55	
			$F_{OUT} > 62.5MHz$.	40		60	
T_{OE}	Output Enable/ Disable Time					100	ns
f_{JITTER}	Phase Jitter (12kHz–20MHz)	LVDS.			300	400	fsec
		LVPECL.			300	400	
		HCSL.			300	400	
		LVCMOS.	$F_{OUT} = 100MHz$.		300	400	

Table 13. 2.5V AC Electrical Characteristics
 $V_{DD} = 2.5V \pm 5\%$, $T_A = -20^\circ\text{C}$ to $+70^\circ\text{C}$; -40°C to $+85^\circ\text{C}$, -40°C to $+105^\circ\text{C}$.

Symbol	Parameter	Test Condition		Minimum	Typical	Maximum	Units
F	Output Frequency Range	LVDS.		0.016		1350	MHz
		LVPECL.		0.75		670	
		HCSL.		0.016		670	
		LVCMOS.		0.016		167	
	Frequency Stability	Temperature = -20°C to $+70^\circ\text{C}$.		± 20		± 100	ppm
		Temperature = -40°C to $+85^\circ\text{C}$.		± 25		± 100	ppm
		Temperature = -40°C to $+105^\circ\text{C}$.		± 50		± 100	ppm
	Aging (1st year)	$T_A = 25^\circ\text{C}$.				± 3	
	Aging (10 years)	$T_A = 25^\circ\text{C}$.				± 10	
	Output Load	LVDS.	Differential.		100		Ω
		LVPECL.	$V_{DD} - 2.0V$.		50		
		HCSL.	To GND.		50		
		LVCMOS.	To GND.		15		pF
T_{ST}	Start-up Time	Output valid time after V_{DD} meets minimum specified level.				10	ms
t_R	Output Rise Time	LVDS.	20% to 80% Vpk-pk.		300	400	ps
		LVPECL.			250	630	
		HCSL.				315	
		LVCMOS.	10% to 90% V_{DD} .			3	ns
t_F	Output Fall Time	LVDS.	80% to 20% Vpk-pk.		300	400	ps
		LVPECL.			360	630	
		HCSL.				315	
		LVCMOS.	90% to 10% V_{DD} .			3	ns
O_{DC}	Output Clock Duty Cycle	LVDS.		45		55	%
		LVPECL.	$F_{OUT} \leq 156.25\text{MHz}$.	45		55	
			$F_{OUT} \leq 156.25\text{MHz}$.	40		60	
		HCSL.		45		55	
		LVCMOS.	$F_{OUT} \leq 62.5\text{MHz}$.	45		55	
			$F_{OUT} > 62.5\text{MHz}$.	40		60	
T_{OE}	Output Enable/ Disable Time					100	ns
f_{JITTER}	Phase Jitter (12kHz–20MHz)	LVDS.			400	500	fsec
		LVPECL.			350	500	
		HCSL.			350	500	
		LVCMOS.	$F_{OUT} = 100\text{MHz}$.		350	500	

Table 14. 1.8V AC Electrical Characteristics
 $V_{DD} = 1.8V \pm 5\%$, $T_A = -20^\circ C$ to $+70^\circ C$; $-40^\circ C$ to $+85^\circ C$, $-40^\circ C$ to $+105^\circ C$.

Symbol	Parameter	Test Condition		Minimum	Typical	Maximum	Units
F	Output Frequency Range	LVDS.		0.016		1000	MHz
		LVPECL, HCSL.		0.016		670	
		LVCMOS.		0.016		125	
	Frequency Stability	Temperature = $-20^\circ C$ to $+70^\circ C$.		± 20		± 100	ppm
		Temperature = $-40^\circ C$ to $+85^\circ C$.		± 25		± 100	ppm
		Temperature = $-40^\circ C$ to $+105^\circ C$.		± 50		± 100	ppm
	Aging (1st year)	$T_A = 25^\circ C$.				± 3	
	Aging (10 years)	$T_A = 25^\circ C$.				± 10	
	Output Load	LVDS.	Differential.		100		Ω
		LVPECL, HCSL.	To GND.		50		
		LVCMOS.	To GND.		10		pF
T_{ST}	Start-up Time	Output valid time after V_{DD} meets minimum specified level.				10	ms
t_R	Output Rise Time	LVDS.	20% to 80% Vpk-pk.		250	315	ps
		LVPECL.			250	350	
		HCSL.				320	
		LVCMOS.	10% to 90% V_{DD} .		5		ns
t_F	Output Fall Time	LVDS.	80% to 20% Vpk-pk.		250	315	ps
		LVPECL.			250	350	
		HCSL.				320	
		LVCMOS.	90% to 10% V_{DD} .		5		ns
O_{DC}	Output Clock Duty Cycle	LVDS.	$F_{OUT} \leq 156.25MHz$.	45		55	%
			$F_{OUT} \leq 156.25MHz$.	40		60	
		LVPECL.	$F_{OUT} \leq 312.5MHz$.	45		55	
			$F_{OUT} > 312.5MHz$.	40		60	
		HCSL.		40		60	
		LVCMOS.	$F_{OUT} \leq 62.5MHz$.	45		55	
			$F_{OUT} > 62.5MHz$.	40		60	
T_{OE}	Output Enable/ Disable Time					100	ns
f_{JITTER}	Phase Jitter (12kHz–20MHz)	LVDS.			800	1200	fsec
		LVPECL.			750	1200	
		HCSL.			100	1200	
		LVCMOS.	$F_{OUT} = 100MHz$.		800	1200	

Notes for all AC Electrical Characteristics tables:

- ¹ A pull-up resistor from V_{DD} to E/D enables output when pin 1 is left open.
- ² Installation should include a 0.01 μ F bypass capacitor placed between VDD and GND to minimize power supply line noise.
- ³ Stability is inclusive of 25°C tolerance, operating temperature range, input voltage change, load change, aging, shock and vibration.
- ⁴ Standard LVCMOS frequencies include 10MHz, 12MHz, 12.288MHz, 16MHz, 20MHz, 24MHz, 24.576MHz, 25MHz, 33.333MHz, 40MHz, 48MHz, 50MHz, 100MHz, 125MHz and 156.25MHz.
- ⁵ Standard differential frequencies include 100MHz, 106.25MHz, 125MHz, 150MHz, 155.52MHz, 156.25MHz, 200MHz, 212.5MHz, 250MHz, 300MHz, 312.5MHz and 400MHz.

I2C Bus Characteristics

Table 15. I2C Bus DC Characteristics

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Level	—	$0.7 \times V_{DD33}$	—	—	V
V_{IL}	Input Low Level	—	—	—	$0.3 \times V_{DD33}$	V

Table 16. I2C Bus AC Characteristics

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
F_{SCLK}	Serial Clock Frequency (SCL)	—	—	100	400	kHz
t_{BUF}	Bus Free Time between STOP and START	—	1.3	—	—	μ s
$t_{SU:START}$	Setup Time, START	—	0.6	—	—	μ s
$t_{HD:START}$	Hold Time, START	—	0.6	—	—	μ s
$t_{SU:DATA}$	Setup Time, Data Input (SDA)	—	100	—	—	μ s
$t_{HD:DATA}$	Hold Time, Data Input (SDA) ¹	—	0	—	—	μ s
t_R	Rise Time, Data and Clock (SDA, SCL)	—	—	—	300	ns
t_F	Fall Time, Data and Clock (SDA, SCL)	—	—	—	300	ns
t_{HIGH}	High Time, Clock (SCL)	—	0.6	—	—	μ s
t_{LOW}	Low Time, Clock (SCL)	—	1.3	—	—	μ s
$t_{SU:STOP}$	Setup Time, STOP	—	0.6	—	—	μ s

¹ A device must internally provide a hold time of at least 300ns for the SDA signal (referred to the $V_{IH(MIN)}$ of the SCL signal) to bridge the undefined region of the falling edge of SCL.

Output Waveforms

Figure 1. LVDS Output Waveforms

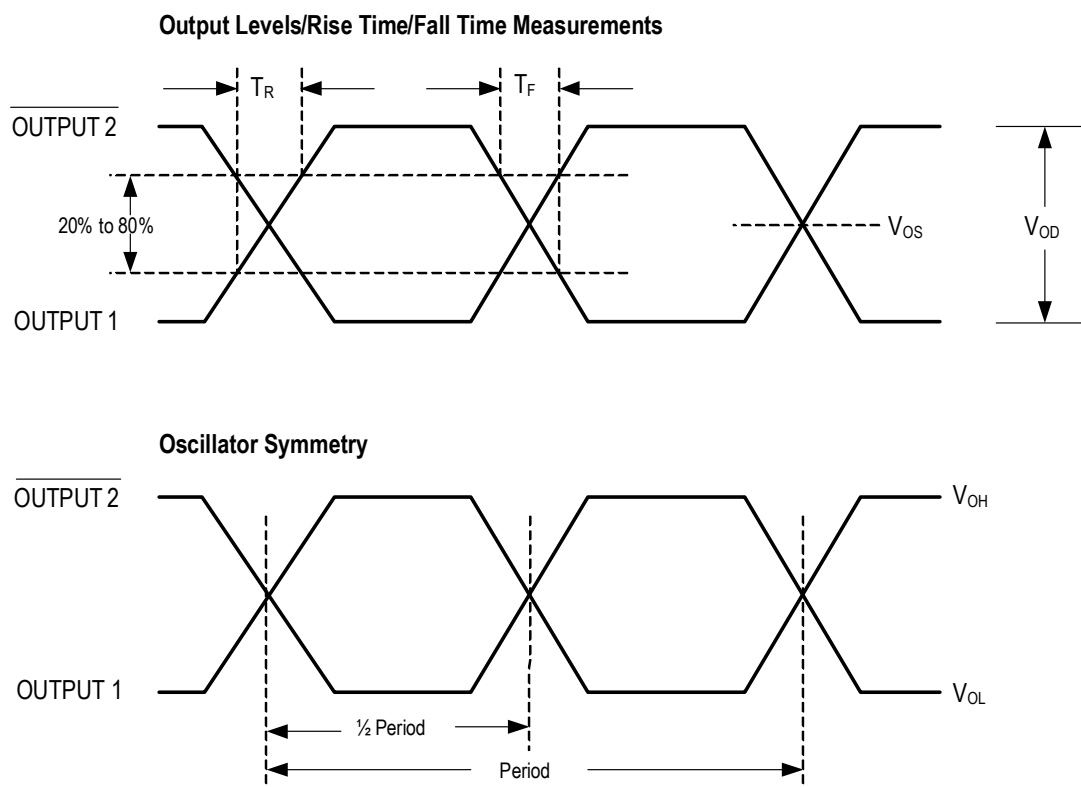


Figure 2. LVPECL Output Waveforms

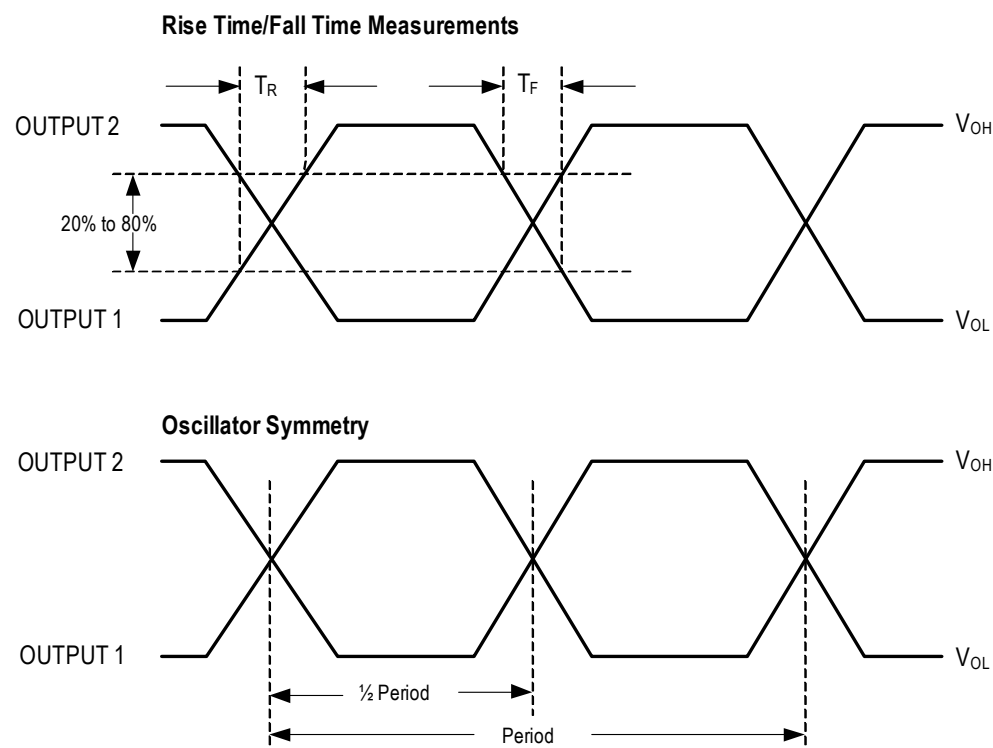


Figure 3. HCSL Output Waveforms

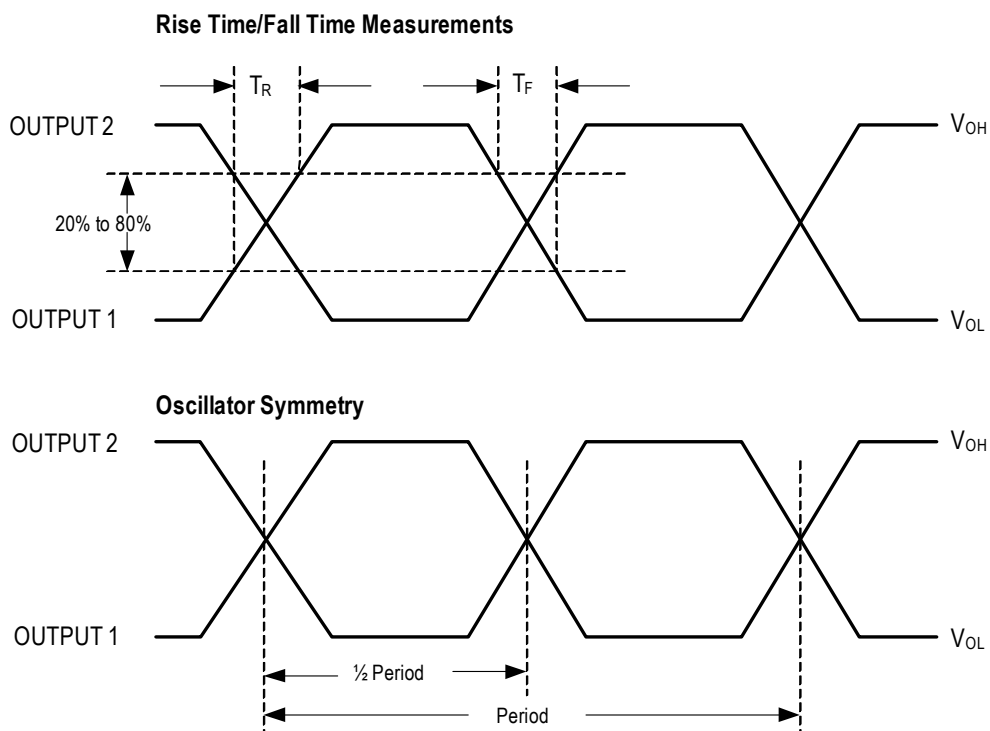
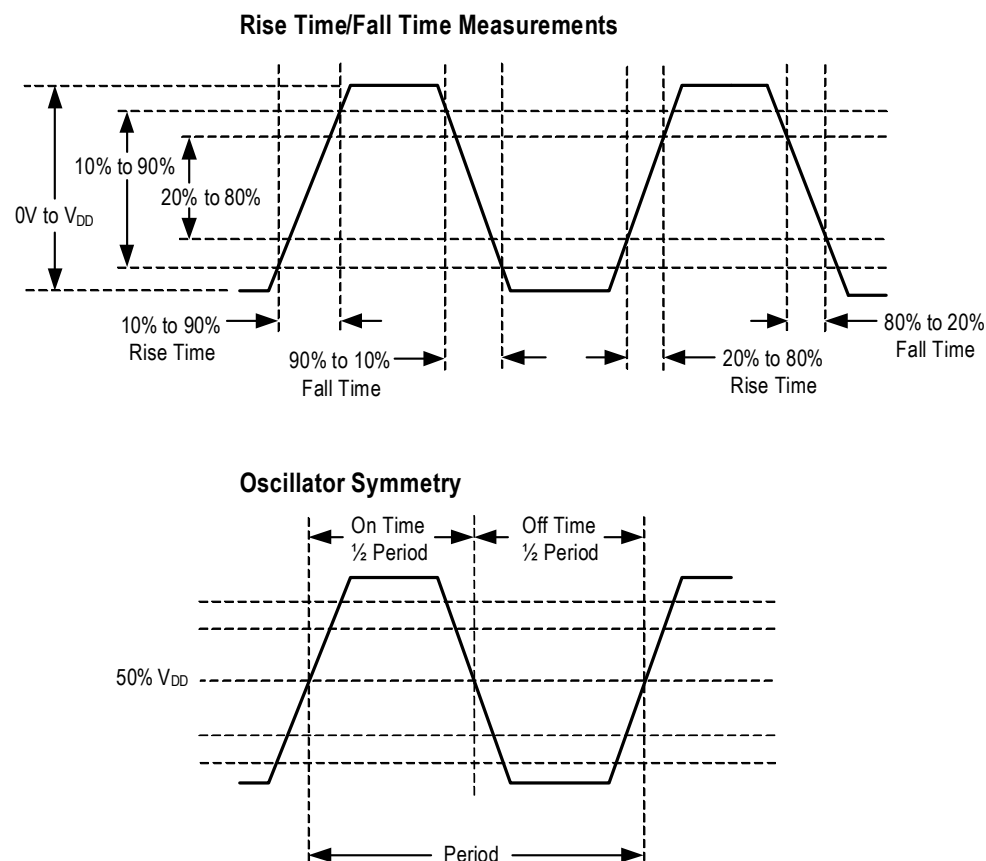


Figure 4. LVCMOS Output Waveforms

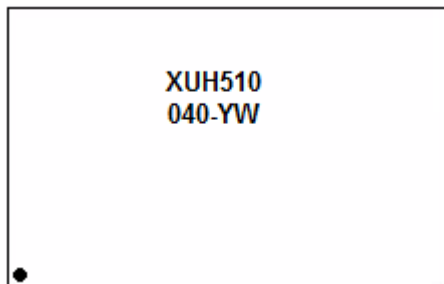


Package Outline Drawings

The package outline drawings (JS6, JU6) are appended at the end of this document. The package information is the most current data available.

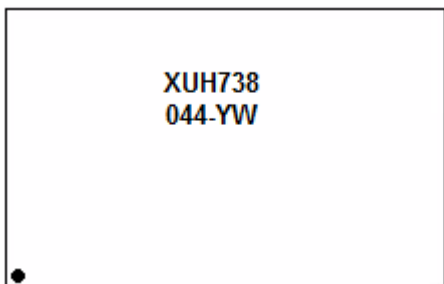
Marking Diagrams

JS6 5.0 × 3.2 mm Package Option (example based on XUH510040.000000I)



- Line 1:
 - “XU” = family; “H” = output type; “5” = package size; “1” = voltage; “0” = precision level. This number will vary depending upon the output type, voltage, and precision values selected in the orderable part number.
- Line 2:
 - “040” denotes last three digits to the left of the decimal point as shown in the above example. This number will vary depending upon the frequency value selected in the orderable part number.
 - “YW” denotes the last digit of the year and work week the part was assembled.

JU6 7.0 × 5.0 mm Package Option (example based on XUH738044.736000X)

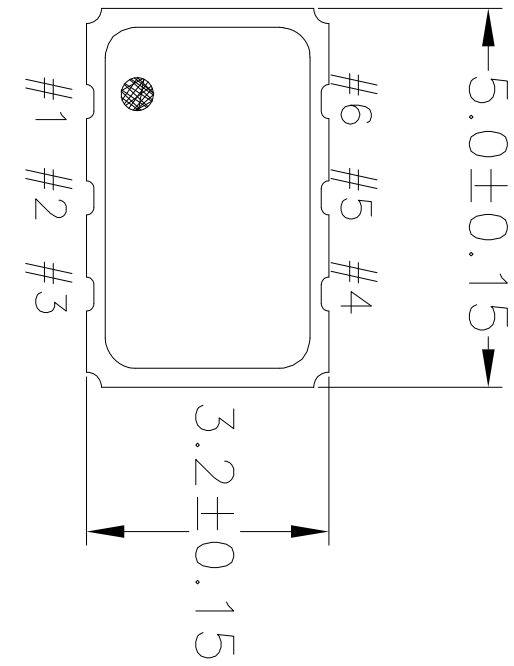


- Line 1:
 - “XU” = family; “H” = output type; “7” = package size; “3” = voltage; “8” = precision level. This number will vary depending upon the output type, voltage, and precision values selected in the orderable part number.
- Line 2:
 - “044” denotes last three digits to the left of the decimal point as shown in the above example. This number will vary depending upon the frequency value selected in the orderable part number.
 - “YW” denotes the last digit of the year and work week the part was assembled.

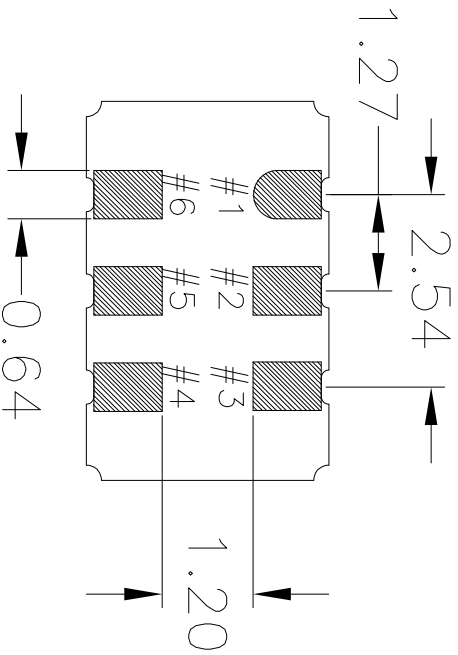
Revision History

Revision Date	Description of Change
August 18, 2021	Moved Ordering Information table to just after Pin Descriptions.
January 19, 2021	- Removed 4-pin package description table, figure, and package drawing references. - Added footnote for pin 5 in Table 1. - Added footnote under "Output Type" in Ordering Information.
January 12, 2021	Added Marking Diagrams section and updated Package Outline Drawings links.
February 11, 2020	Added I2C Bus Characteristics tables.
June 28, 2019	Added footnote to frequency range bullet under front page Features.
June 25, 2018	Updated Package Outline Drawings section.
November 22, 2017	- Updated Theta JA and JB in Absolute Maximum Ratings table. - Added MSL statement under Mechanical Testing table. - Updated ordering information.
October 19, 2017	- Updated document title. - Updated Features bullets. - Updated Absolute Maximum Ratings and ESD Compliance tables. - Added -40°C to +105°C rating to all electrical tables. - Removed phase noise charts. - Updated Ordering Information table.
May 12, 2017	- Reformatted embedded tables. - Removed "Jitter Performance" tables and moved the "Phase Jitter (12kHz–20MHz)" parameter to its respective AC Electrical Characteristics table. - Updated all Output Waveform drawings.
December 1, 2016	Initial release.

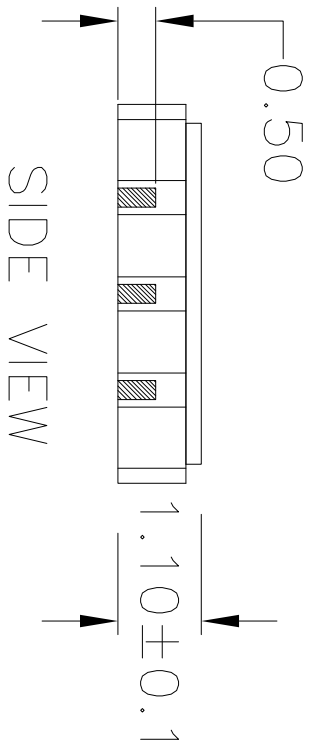
REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	04/2/12	DP
01	ADDED LID IN TOP VIEW	07/12/12	KS
02	UPDATED LID TOLERANCES	12/03/12	KS
03	UPDATE PACKAGE DRAWING	8/8/14	JHUA



TOP VIEW



BOTTOM VIEW



SIDE VIEW

NOTES:
1. ALL DIMENSIONS IN MM.

TOLERANCES
UNLESS SPECIFIED

DECIMAL	ANGULAR
XX±	±
XXX±	
XXXX±	

IDT™

6024 Silver Creek Valley Rd
San Jose, CA 95138
PHONE: (408) 727-6116
FAX: (408) 492-8574

www.IDT.com

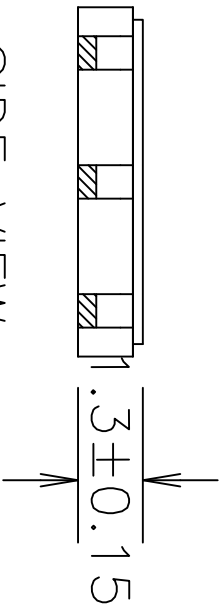
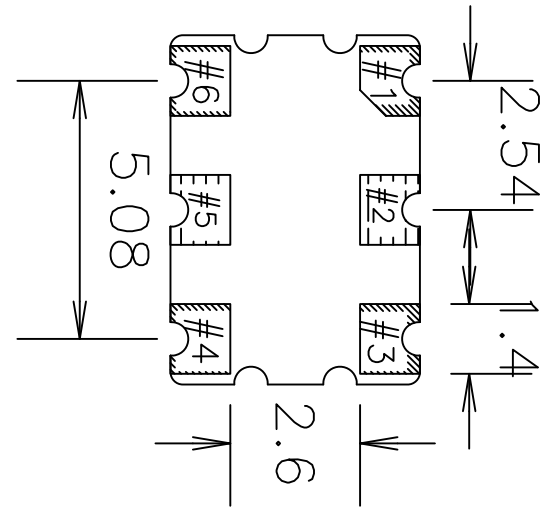
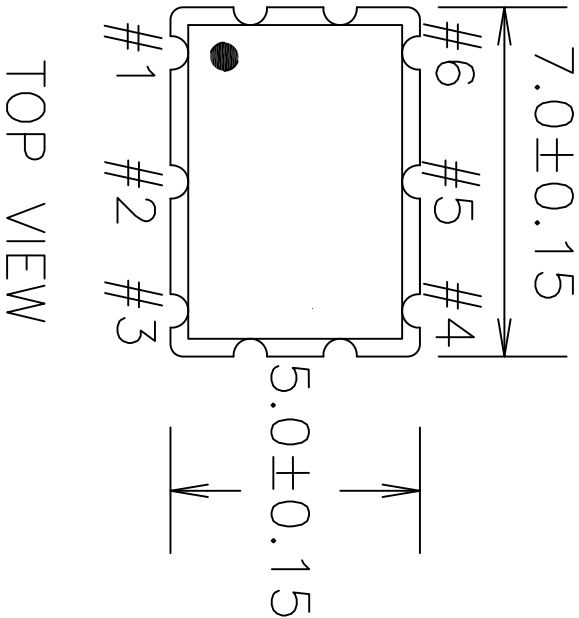
APPROVALS	DATE	TITLE
DRAWN <i>02AC</i>	04/2/12	JS6 PACKAGE OUTLINE
CHECKED		5.0 x 3.2 mm BODY
		1.1 mm Thick

SIZE	DRAWING No.	REV
C	PSC-4411	03

DO NOT SCALE DRAWING

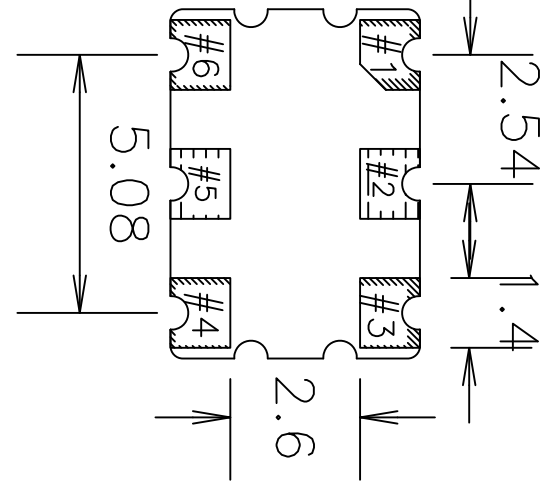
SHEET 1 OF 2

REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	10/5/12	KS
01	UPDATE PACKAGE DRWING	8/12/14	JHUA



SIDE VIEW

BOTTOM VIEW

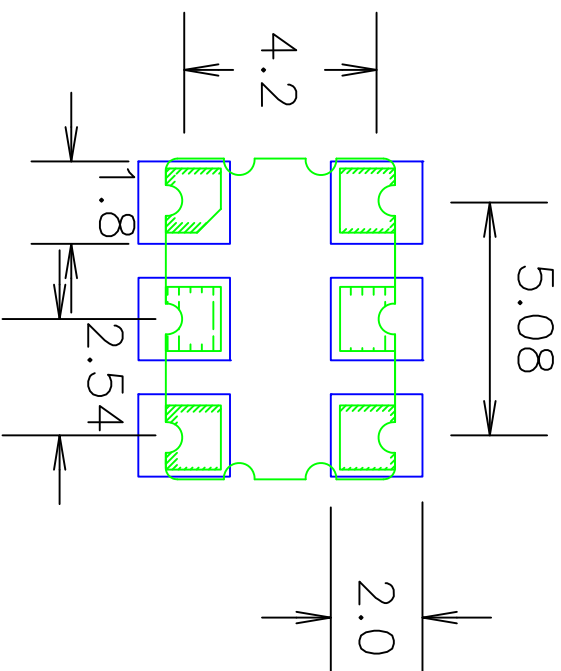


NOTES:

1. ALL DIMENSIONS IN MM.

TOLERANCES UNLESS SPECIFIED		6024 Silver Creek Valley Rd	
DECIMAL	ANGULAR	San Jose, CA 95138	
XXX±	±	PHONE: (408) 727-6116	
XXXX±		FAX: (408) 482-9874	
XXXX±		www.IDT.com	
APPROVALS	DATE	TITLE	
DRAWN XJS	10/03/12	J16 PACKAGE OUTLINE	
CHECKED		7.0 x 5.0 mm BODY	
		1.3 mm Thick	
		SIZE	
		C	
		DRAWING No.	
		PSC-4430	
		REV	
		01	
DO NOT SCALE DRAWING		SHEET 1 OF 2	

REVISIONS			
REV	DESCRIPTION	DATE	APPROVED
00	INITIAL RELEASE	10/5/12	KS
01	UPDATE PACKAGE DRAWING	8/12/14	J.HUA



RECOMMENDED LAND PATTERN

- NOTES:
1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
 2. TOP DOWN VIEW. AS VIEWED ON PCB.
 3. COMPONENT OUTLINE SHOW FOR REFERENCE IN GREEN.
 4. LAND PATTERN IN BLUE. NSMD PATTERN ASSUMED.
 5. LAND PATTERN RECOMMENDATION PER IPC-7351B. GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

TOLERANCES UNLESS SPECIFIED			
DECIMAL	ANGULAR		
XX.X	±		
XX.XX			
XX.XXX			
APPROVALS	DATE		
DRAWN JS	10/05/12		
CHECKED			
SIZE	DRAWING No.		
C	FSC-4430		
		REV	01
DO NOT SCALE DRAWING		SHEET 2 OF 2	

IDT
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San Jose, CA 95138
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TITLE J06 PACKAGE OUTLINE
7.0 x 5.0 mm BODY
1.3 mm Thick

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(Rev.1.0 Mar 2020)

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